

Package: Module, 22.86 mm x 22.86 mm x 13.97 mm

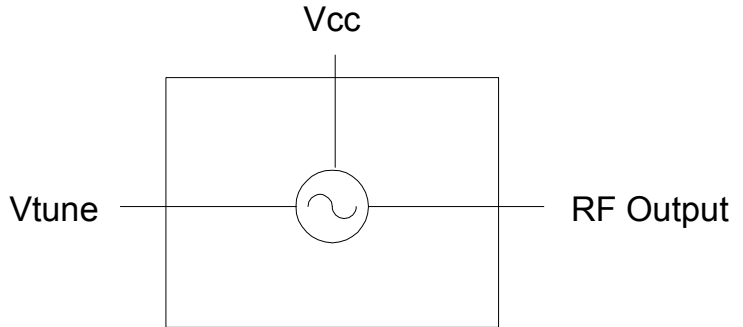


**Features**

- 50MHz to 100MHz VCO
- 15V Operation
- +13.0dBm Typical Output Power
- -108dBc/Hz at 10kHz
- -128dBc/Hz at 100kHz
- -148dBc/Hz at 1000kHz

**Applications**

- Instrumentation
- Aerospace
- Test Equipment
- Plug and Play



Functional Block Diagram

**Product Description**

RFMD's VCO-103S/STC is a hybrid assembled voltage controlled oscillator integrated into a connectorized module. The VCO-103 features an integrated resonator and tuning varactors. The part features excellent performance over temperature.

**Ordering Information**

VCO-103S/STC      High Reliability Military and Space VCO

**Optimum Technology Matching® Applied**

- |                                      |                                      |  |                                    |
|--------------------------------------|--------------------------------------|--|------------------------------------|
| <input type="checkbox"/> GaAs HBT    | <input type="checkbox"/> SiGe BiCMOS | <input type="checkbox"/> GaAs pHEMT        | <input type="checkbox"/> GaN HEMT  |
| <input type="checkbox"/> GaAs MESFET | <input type="checkbox"/> Si BiCMOS   | <input type="checkbox"/> Si CMOS           | <input type="checkbox"/> BIFET HBT |
| <input type="checkbox"/> InGaP HBT   | <input type="checkbox"/> SiGe HBT    | <input checked="" type="checkbox"/> Si BJT | <input type="checkbox"/> LDMOS     |

RF MICRO DEVICES®, RFMD®, Optimum Technology Matching®, Enabling Wireless Connectivity™, PowerStar®, POLARIS™ TOTAL RADIO™ and UltimateBlue™ are trademarks of RFMD, LLC. BLUETOOTH is a trademark owned by Bluetooth SIG, Inc., U.S.A. and licensed for use by RFMD. All other trade names, trademarks and registered trademarks are the property of their respective owners. ©2006, RF Micro Devices, Inc.

## Absolute Maximum Ratings

Parameter	Rating	Unit
Supply Voltage ( $V_{CC}$ )	17	V
$V_{TUNE}$	0 to 22	V
Storage Temperature	-65 to 150	°C
Operating Temperature	-55 to 100	°C
ESD JESD22 - A114 Human Body Model (HBM)		V



**Caution!** ESD sensitive device.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implied.

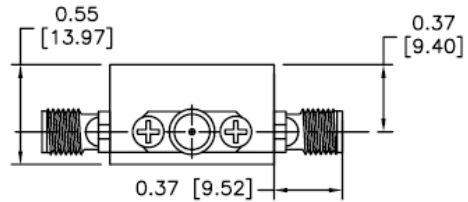
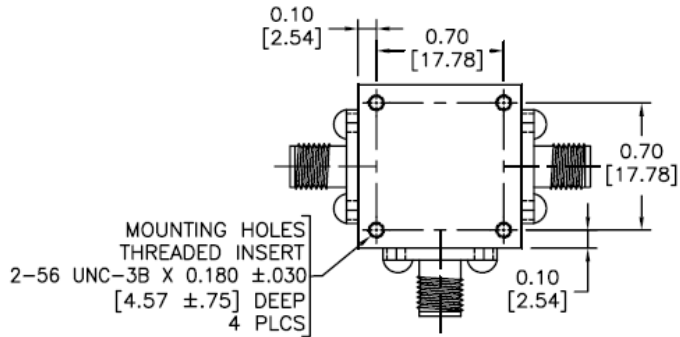
RoHS status based on EUDirective2002/95/EC (at time of this document revision).

The information in this publication is believed to be accurate and reliable. However, no responsibility is assumed by RF Micro Devices, Inc. ("RFMD") for its use, nor for any infringement of patents, or other rights of third parties, resulting from its use. No license is granted by implication or otherwise under any patent or patent rights of RFMD. RFMD reserves the right to change component circuitry, recommended application circuitry and specifications at any time without prior notice.

Parameter	Specification			Unit	Condition
	Min.	Typ.	Max.		
<b>Frequency</b>					
Frequency Range	50		100	MHz	100% Production Tested
<b>Tuning Voltage</b>					
50MHz	0	1.4		$V_{DC}$	100% Production Tested
100MHz		16.4	20	$V_{DC}$	100% Production Tested
<b>Tuning Sensitivity</b>					
50MHz	1.8	2.4	3	MHz/V	100% Production Tested
62.5MHz	2.7	3.6	4.5	MHz/V	100% Production Tested
75MHz	2.9	3.8	4.8	MHz/V	100% Production Tested
87.5MHz	2.8	3.7	4.7	MHz/V	100% Production Tested
100MHz	1.6	2.1	2.7	MHz/V	100% Production Tested
Output Power	10	13.0	16	dBm	100% Production Tested
<b>Output Phase Noise</b>					
10kHz		-108	-102	dBc/Hz	100% Production Tested
100kHz		-128	-122	dBc/Hz	100% Production Tested
1000kHz		-148	-142	dBc/Hz	100% Production Tested
Power Supply	14.75	15	15.25	V	100% Production Tested
Supply Current		12.5	15	mA	100% Production Tested
<b>Harmonic Suppression</b>					
2nd Harmonic		-12	-10	dBc	100% Production Tested
3rd Harmonic		-12	-10	dBc	100% Production Tested
<b>Spurious (Non-Harmonic)</b>					
Frequency Pushing		0.05	0.2	MHz p-p	14.75V to 15.25V
Frequency Pulling		1	3	MHz p-p	12dB RL
Output Impedance		50		$\Omega$	
3dB Modulation Bandwidth	100	175		kHz	$Z_G = 50\Omega$
Tune Port Impedance (DC)		50		k $\Omega$	

Pin	Function	Description
1	VTUNE	Tuning voltage.
2	VCC	Supply voltage.
3	RF Output	VCO RF output.

**Pin Out and Package Drawing**



PINOUT	FUNCTION		
	VCO	MIXER	POWER DIVIDER
1	TUNING VOLTAGE	RF PORT	OUT 2
2	SUPPLY VOLTAGE	X PORT	IN
3	RF OUTPUT	LO PORT	OUT 1

